

BFR182W

Low Noise Silicon Bipolar RF Transistor

- For low noise, high-gain broadband amplifiers at collector currents from 1 mA to 20 mA
- $f_{\rm T}$ = 8 GHz, *NF*_{min} = 0.9 dB at 900 MHz
- Pb-free (RoHS compliant) and halogen-free package with visible leads
- Qualification report according to AEC-Q101 available





ESD (Electrostatic discharge) sensitive device, observe handling precaution!

| Туре | Marking | Pin Configuration | | | Package |
|---------|---------|-------------------|-----|-----|---------|
| BFR182W | RGs | 1=B | 2=E | 3=C | SOT323 |

Maximum Ratings at T_A = 25 °C, unless otherwise specified

| Parameter | Symbol | Value | Unit | |
|---------------------------------------|------------------|---------|------|--|
| Collector-emitter voltage | V _{CEO} | 12 | V | |
| Collector-emitter voltage | V _{CES} | 20 | | |
| Collector-base voltage | V _{CBO} | 20 | | |
| Emitter-base voltage | V _{EBO} | 2 | | |
| Collector current | I _C | 35 | mA | |
| Base current | I _B | 4 | | |
| Total power dissipation ¹⁾ | P _{tot} | 250 | mW | |
| <i>T</i> _S ≤ 90 °C | | | | |
| Junction temperature | T _J | 150 | °C | |
| Ambient temperature | T _A | -65 150 | | |
| Storage temperature | T _{Stg} | -65 150 | | |

| Parameter | Symbol | Value | Unit |
|--|-------------------|-------|------|
| Junction - soldering point ²⁾ | R _{thJS} | 240 | K/W |

 ${}^{1}T_{S}$ is measured on the collector lead at the soldering point to the pcb

²For the definition of R_{thJS} please refer to Application Note AN077 (Thermal Resistance Calculation)



| Parameter | Symbol | Symbol | | Values | |
|---|----------------------|--------|------|--------|----|
| | | min. | typ. | max. | |
| DC Characteristics | | | | | |
| Collector-emitter breakdown voltage | V _{(BR)CEO} | 12 | - | - | V |
| <i>I</i> _C = 1 mA, <i>I</i> _B = 0 | | | | | |
| Collector-emitter cutoff current | I _{CES} | | | | nA |
| $V_{\rm CE}$ = 4 V, $V_{\rm BE}$ = 0 | | - | 1 | 30 | |
| V_{CE} = 15 V, V_{BE} = 0 V, T_{A} = 85 °C | | - | 5 | 70 | |
| (verified by random sampling) | | | | | |
| Collector-base cutoff current | I _{CBO} | - | 1 | 30 | |
| $V_{\rm CB}$ = 4 V, $I_{\rm E}$ = 0 | | | | | |
| Emitter-base cutoff current | I _{EBO} | - | - | 50 |] |
| $V_{\rm EB}$ = 1 V, $I_{\rm C}$ = 0 | | | | | |
| DC current gain | h _{FE} | 70 | 100 | 140 | - |
| $I_{\rm C}$ = 10 mA, $V_{\rm CE}$ = 8 V, pulse measured | | | | | |

Electrical Characteristics at T_A = 25 °C, unless otherwise specified



| Parameter | Symbol | Values | | | Unit |
|--|---------------------------------|--------|------|------|------|
| | | min. | typ. | max. | |
| AC Characteristics (verified by random sampling) | | | | | |
| Transition frequency | f _T | 6 | 8 | - | GHz |
| <i>I</i> _C = 15 mA, <i>V</i> _{CE} = 8 V, <i>f</i> = 500 MHz | | | | | |
| Collector-base capacitance | C _{cb} | - | 0.34 | 0.5 | pF |
| $V_{CB} = 10 \text{ V}, f = 1 \text{ MHz}, V_{BE} = 0$, | | | | | |
| emitter grounded | | | | | |
| Collector emitter capacitance | C _{ce} | - | 0.26 | - | |
| $V_{CE} = 10 \text{ V}, f = 1 \text{ MHz}, V_{BE} = 0$, | | | | | |
| base grounded | | | | | |
| Emitter-base capacitance | C _{eb} | - | 0.8 | - | |
| V _{EB} = 0.5 V, <i>f</i> = 1 MHz, V _{CB} = 0 , | | | | | |
| collector grounded | | | | | |
| Minimum noise figure | NF _{min} | | | | dB |
| $I_{\rm C}$ = 3 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm Sopt}$, | | | | | |
| <i>f</i> = 900 MHz | | - | 0.9 | - | |
| $I_{\rm C}$ = 3 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm Sopt}$, | | | | | |
| <i>f</i> = 1.8 GHz | | - | 1.3 | - | |
| Power gain, maximum stable ¹⁾ | G _{ms} | - | 19 | - | dB |
| $I_{\rm C}$ = 10 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm Sopt}$, $Z_{\rm L}$ = $Z_{\rm Lopt}$, | | | | | |
| <i>f</i> = 900 MHz | | | | | |
| Power gain, maximum available ²⁾ | G _{ma} | - | 12.5 | - | dB |
| $I_{\rm C}$ = 10 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm Sopt}$, $Z_{\rm L}$ = $Z_{\rm Lopt}$, | | | | | |
| <i>f</i> = 1.8 GHz | | | | | |
| Transducer gain | S _{21e} ² | | | | dB |
| $I_{\rm C}$ = 10 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm L}$ = 50 Ω , | | | | | |
| <i>f</i> = 900 MHz | | - | 15.5 | - | |
| $I_{\rm C}$ = 10 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm L}$ = 50 Ω , | | | | | |
| <i>f</i> = 1.8 GHz | | - | 10 | - | |

Electrical Characteristics at $T_A = 25$ °C, unless otherwise specified

 ${}^{1}G_{\rm ms} = |S_{21} / S_{12}|$ ${}^{2}G_{\rm ma} = |S_{21e} / S_{12e}| \ (k - (k^2 - 1)^{1/2})$



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Total power dissipation $P_{tot} = f(T_S)$

Permissible Pulse Load $R_{\text{thJS}} = f(t_p)$



Permissible Pulse Load

 $P_{\text{totmax}}/P_{\text{totDC}} = f(t_{p})$











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